

RoHS

COMPLIANT

HALOGEN

FREE

Available

Vishay Siliconix

P-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY									
V _{DS} (V)	R_{DS(on)} (Ω)	V _{GS(th)} (V)	I _D (mA)	Q _g (Typ.)					
- 30	1.4 at V _{GS} = - 10 V	- 1.3 to - 3.0	- 385	1000					
	3.5 at V _{GS} = - 4.5 V	- 1.3 to - 3.0	- 240						



Marking Code: 2Kwll 2K = Part Number Code for TP0202K w = Week Code // = Lot Traceability

Top View

Ordering Information: TP0202K-T1-E3 (Lead (Pb)-free) TP0202K-T1-GE3 (Lead (Pb)-free and Halogen-free)

FEATURES

- Halogen-free According to IEC 61249-2-21 • Available
- TrenchFET[®] Power MOSFET
- High-Side Switching •
- Low On-Resistance: 1.2 Ω (typ.) •
- Low Threshold: 2 V (typ.) •
- Fast Swtiching Speed: 14 ns (typ.) •
- Low Input Capacitance: 31 pF (typ.)
- 2000 V ESD Protection ٠

APPLICATIONS

- Drivers: Relays, Solenoids, Lamps, Hammers, Display, Memories, Transistors, etc.
- **Battery Operated Systems** ٠
- Power Supply Converter Circuits •
- Solid-State Relays

BENEFITS

- Ease in Driving Switches •
- Low Offset (Error) Voltage •
- Low-Voltage Operation
- **High-Speed Circuits**
- Easily Driven without Buffer •

ABSOLUTE MAXIMUM RATINGS $T_A = 25 \degree C$, unless otherwise noted								
Parameter	Symbol	Limit	Unit					
Drain-Source Voltage	V _{DS}	V _{DS} - 30						
Gate-Source Voltage		V _{GS}	± 20	v				
Continuous Drain Current /T 150 °C\ª	T _A = 25 °C	1_	- 385	mA				
Continuous Drain Current $(T_j = 150 \text{ °C})^{-1}$	T _A = 85 °C	D	- 280					
Pulsed Drain Current ^b		I _{DM}	- 750					
	T _A = 25 °C	Р	350	m\\/				
Power Dissipation"	T _A = 85 °C	гD	185					
Maximum Junction-to-Ambient ^a	R _{thJA}	350	°C/W					
Operating Junction and Storage Temperature Range		$T_{J,}T_{stg}$	- 55 to 150	°C				

Notes:

a. Surface Mounted on FR4 board.

b. Pulse width limited by maximum junction temperature.

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SPECIFICATIONS $T_A = 25 \text{ °C}$, unless otherwise noted										
			Limits							
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit				
Static										
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V$, $I_{D} = -100 \mu A$	- 30	- 38		V				
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \ \mu A$	- 1.3	- 2	- 3.0	v				
Cata Bady Laskaga	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 5 V$			± 50	nA				
Gale-Douy Leakage		$V_{DS} = 0 V, V_{GS} = \pm 10 V$			± 300					
Zara Cata Valtaga Drain Current		$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}$			- 100					
Zero Gale voltage Diam Guitent	'DSS	V_{DS} = - 30 V, V_{GS} = 0 V, T_{J} = 85 °C			- 10	μΑ				
On-State Drain Current ^a	I _{D(on)}	V _{GS} = - 10 V, V _{DS} = - 10 V	- 500			mA				
	Б	V _{GS} = - 4.5 V, I _D = - 50 mA		2.1	3.5	Ω				
Drain-Source On-Resistance [®]	R _{DS(on)}	V _{GS} = - 10 V, I _D = - 500 mA		1.25	1.4					
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 5 V, I _D = - 200 mA		315		mS				
Diode Forward Voltage ^a	V _{SD}	I _S = - 250 mA, V _{GS} = 0 V			- 1.2	V				
Dynamic		•	•			•				
Total Gate Charge	Qg	V - 16 V V - 10 V		1000		рС				
Gate-Source Charge	Q _{gs}	$v_{\rm DS} = -10$ v, $v_{\rm GS} = -10$ v		225						
Gate-Drain Charge	Q _{gd}			175						
Input Capacitance	C _{iss}			31		pF				
Output Capacitance	C _{oss}	$V_{DS} = -15 V, V_{GS} = 0 V$ f = 1 MHz		11						
Reverse Transfer Capacitance	C _{rss}			4						
Switching ^b		·				•				
Turn On Time	t _{d(on)}	V_{DD} = - 15 V, R_L = 75 Ω		9		- ns				
	t _r			6						
Turn Off Time	t _{d(off)}	$\text{I}_{\text{D}}\cong$ - 200 mA, V_{GEN} = - 10 V, R_{G} = 6 Ω		30						
	t _f			20						

Notes:

a. Pulse test: PW \leq 300 μs duty cycle \leq 2 %.

b. Switching time is essentially independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



TP0202K Vishay Siliconix

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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TP0202K



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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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